

REMARKS

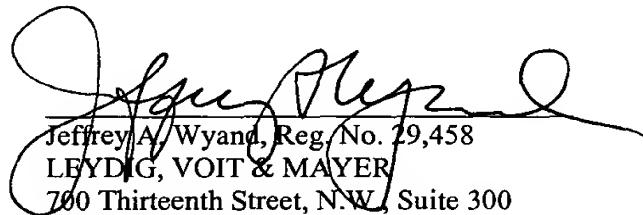
In further response to the Official Action mailed April 4, 2002, Applicants submit a new set of claims, claims 18-25, replacing the previously pending claims. The newly submitted claims are all fully supported by the patent application, particularly with respect to the embodiment illustrated in Figure 4 and the corresponding description. The claims presented here are based on previously submitted claims but have been redrafted in order to avoid awkward language that resulted from the combination of claims presented in the Amendment after Final Rejection.

With regard to the previous rejection, to the extent it may be applied to any of the newly submitted claims, Applicants still respectfully traverse the rejection. Applicants particularly emphasize that the application made of Tsutsui (U.S. Patent 5,925,905) in the previous rejection was incorrect for the reasons stated at page 7 of the Amendment after Final Rejection. Those remarks are incorporated by reference.

In response to the remarks attached to the Advisory Action mailed June 27, 2002, Applicants respectfully emphasize that the prior claims and the claims presented here describe the bending positions of the first and second gate electrodes to be on the insulating regions of the first surface substrate. The assertion that the claims stated that the bends were in the active regions is not consistent with the claim language.

Favorable examination of the claims now presented is earnestly solicited.

Respectfully submitted,


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JAW:ves